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June 2015

Common Drain N-Channel 2.5 V PowerTrench[®] WL-CSP MOSFET

24 V, 7 A, 23 mΩ

Features

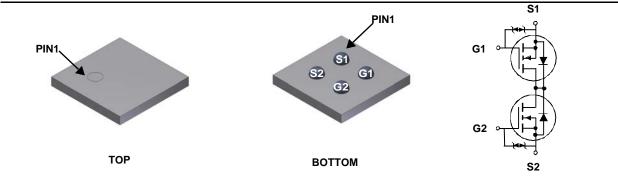
- Max $r_{S1S2(on)}$ = 23 m Ω at V_{GS} = 4.5 V, I_{S1S2} = 1 A
- Max $r_{S1S2(on)} = 25 \text{ m}\Omega$ at $V_{GS} = 4 \text{ V}$, $I_{S1S2} = 1 \text{ A}$
- Max $r_{S1S2(on)}$ = 28 m Ω at V_{GS} = 3.1 V, I_{S1S2} = 1 A
- Max $r_{S1S2(on)}$ = 33 m Ω at V_{GS} = 2.5 V, I_{S1S2} = 1 A
- Occupies only 2.2 mm² of PCB area
- Ultra-thin package: less than 0.35 mm height when mounted to PCB
- High power and current handling capability
- HBM ESD protection level > 3.2 kV (Note 3)
- RoHS Compliant

General Description

This device is designed specifically as a single package solution for Li-Ion battery pack protection circuit and other ultra-portable applications. It features two common drain N-channel MOSFETs, which enables bidirectional current flow, on Fairchild's advanced PowerTrench[®] process with state of the art "low pitch" WLCSP packaging process, the FDZ1416NZ minimizes both PCB space and $r_{S1S2(on)}$. This advanced WLCSP MOSFET embodies a breakthrough in packaging technology which enables the device to combine excellent thermal transfer characteristics, ultra-low profile packaging, low gate charge and low $r_{S1S2(on)}$.

Applications

- Battery management
- Load switch
- Battery protection



WL-CSP 1.4X1.6

MOSFET Maximum Ratings $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	P	arameter		Ratings	Units	
V _{S1S2}	Source1 to Source2 Voltage			24	V	
V _{GS}	Gate to Source Voltage			±12	V	
I	Source1 to Source2 Current -Cor	ntinuous T _A = 25°C	(Note 1a)	7		
I _{S1S2}	-Pulsed			30	— A	
D	Power Dissipation	T _A = 25°C	(Note 1a)	1.7	14/	
P _D	Power Dissipation	T _A = 25°C	(Note 1b)	0.5	W	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	74	°C/W	
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	230	C/ W	

Package Marking and Ordering Information

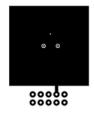
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
EN	FDZ1416NZ	WL-CSP 1.4X1.6	7 "	8 mm	5000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
I _{S1S2}	Zero Gate Voltage Source1 to Source2 Current	$V_{S1S2} = 19 V, V_{GS} = 0 V$			1	μΑ	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 12 \text{ V}, V_{S1S2} = 0 \text{ V}$			±10	μA	
On Chara	octeristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{S1S2}, I_{S1S2} = 250 \ \mu A$	0.4	0.9	1.3	V	
	Static Source1 to Source2 On Resistance	V _{GS} = 4.5 V, I _{S1S2} = 1 A	9	16	23	mΩ	
		V _{GS} = 4 V, I _{S1S2} = 1 A	10	17	25		
r _{S1S2(on)}		V _{GS} = 3.1 V, I _{S1S2} = 1 A	11	19	28		
· · /		V _{GS} = 2.5 V, I _{S1S2} = 1 A	12	22	33	1	
		V _{GS} = 4.5 V, I _{S1S2} = 1 A,T _J = 125 ^o C		24	36]	
9 _{FS}	Forward Transconductance	V _{S1S2} = 5 V, I _{S1S2} = 1 A		4.5		S	
•	Characteristics	· · · · · · · · · · · · · · · · · · ·					
C _{iss}	Input Capacitance	V _{S1S2} = 12 V, V _{GS} = 0 V, f = 1 MHz		1140	1515	pF	
C _{oss}	Output Capacitance			136	220	pF	
C _{rss}	Reverse Transfer Capacitance			129	205	pF	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			9.5	19	ns	
	Rise Time	V_{S1S2} = 12 V, I _{S1S2} = 1 A, V _{GS} = 4.5 V, R _{GEN} = 6 Ω		12	22	ns	
t _r				37	59	ns	
	Turn-Off Delay Time	V_{GS} = 4.5 V, R_{GEN} = 6 Ω					
t _{d(off)}		$V_{GS} = 4.5 V, R_{GEN} = 6 \Omega$		16	33	ns	
t _{d(off)} t _f	Turn-Off Delay Time			16 12	33 17	ns nC	
$\begin{array}{c} t_r \\ t_{d(off)} \\ t_f \\ Q_g \\ Q_{gs} \end{array}$	Turn-Off Delay Time Fall Time	$V_{GS} = 4.5 \text{ V}, \text{ K}_{GEN} = 6 \Omega$ $V_{S1S2} = 12 \text{ V}, \text{ I}_{S1S2} = 1 \text{ A},$ $V_{G1S1} = 4.5 \text{ V}, \text{ V}_{G2S2} = 0 \text{ V}$		-		-	

Source1 to Source2 Diode Characteristics

I _{fss}	Maximum Continuous Source1 to Source2 Diode Forward Current			1	А	
V _{fss}	Source1 to Source2 Diode Forward	$V_{G1S1} = 0 V, V_{G2S2} = 4.5 V,$		0.7	1.2	V
V _{fss}	Voltage	$I_{fss} = 1 A$ (Note 2)		0.7	1.2	

Notes: 1. $R_{\theta,JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta,JC}$ is guaranteed by design while $R_{\theta,CA}$ is determined by the user's board design.



a. 74 °C/W when mounted on a 1 in² pad of 2 oz copper



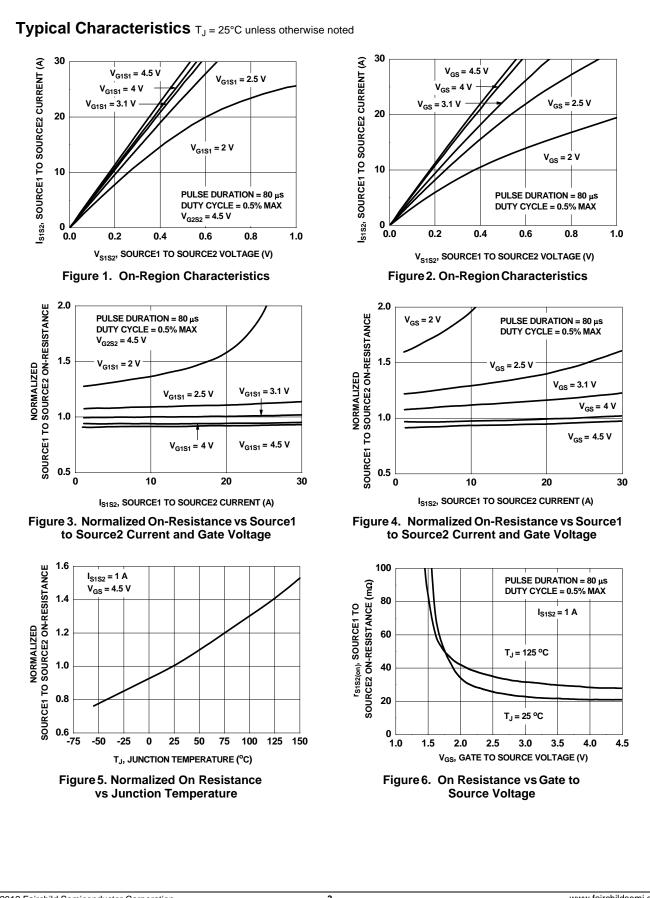
b. 230 °C/W when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300 us, Duty cycle < 2.0%.

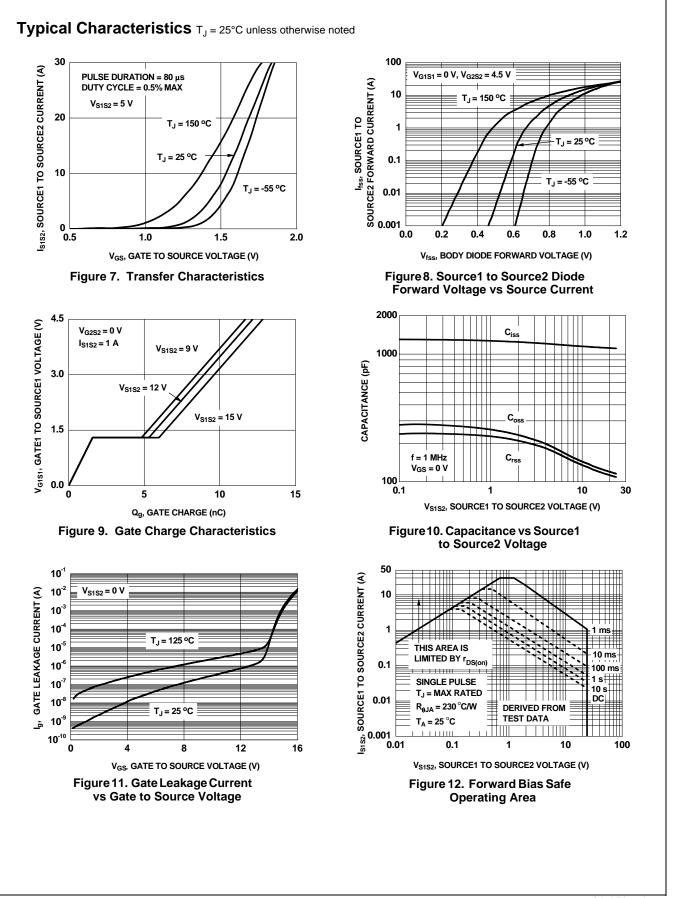
3. The diode connected between the gate and source serves only protection against ESD. No gate overvoltage rating is implied.



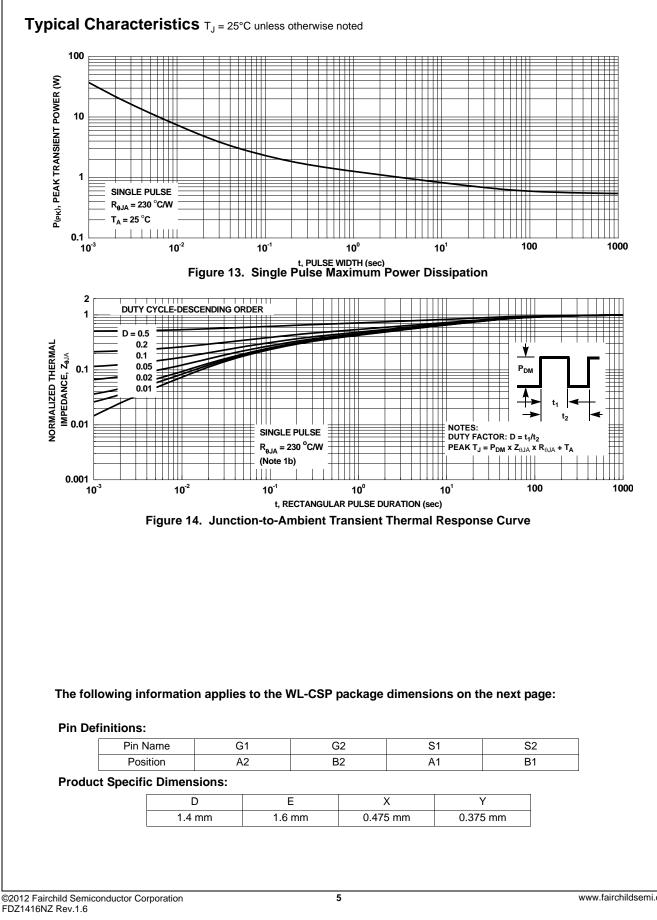


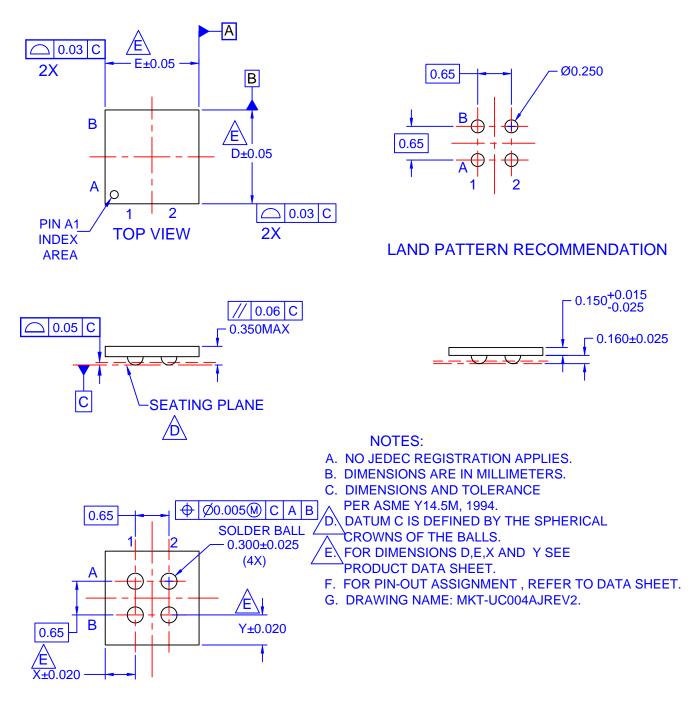


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FDZ1416NZ Common Drain N-Channel 2.5 V PowerTrench[®] WL-CSP MOSFET





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